

AC INPUT RESPONSE
DARLINGTON TRANSISTOR
SOP MULTI PHOTOCOUPLER SERIES

-NEPOC Series-

DESCRIPTION

The PS2706-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon darlington-connected phototransistor.

This is mounted in a plastic SOP (Small Out-line Package) for high density applications.

This package has shield effect to cut off ambient light.

FEATURES

- AC input response
- High current transfer ratio (CTR = 2 000 % TYP.)
- High isolation voltage (BV = 3 750 Vr.m.s.)
- Small and thin (SOP) package
- High-speed switching (t_r , t_f = 200 μ s TYP.)
- Ordering number of taping product: PS2706-1F3, F4
- UL approved: File No. E72422 (S)
- VDE0884 approved (Option)

APPLICATIONS

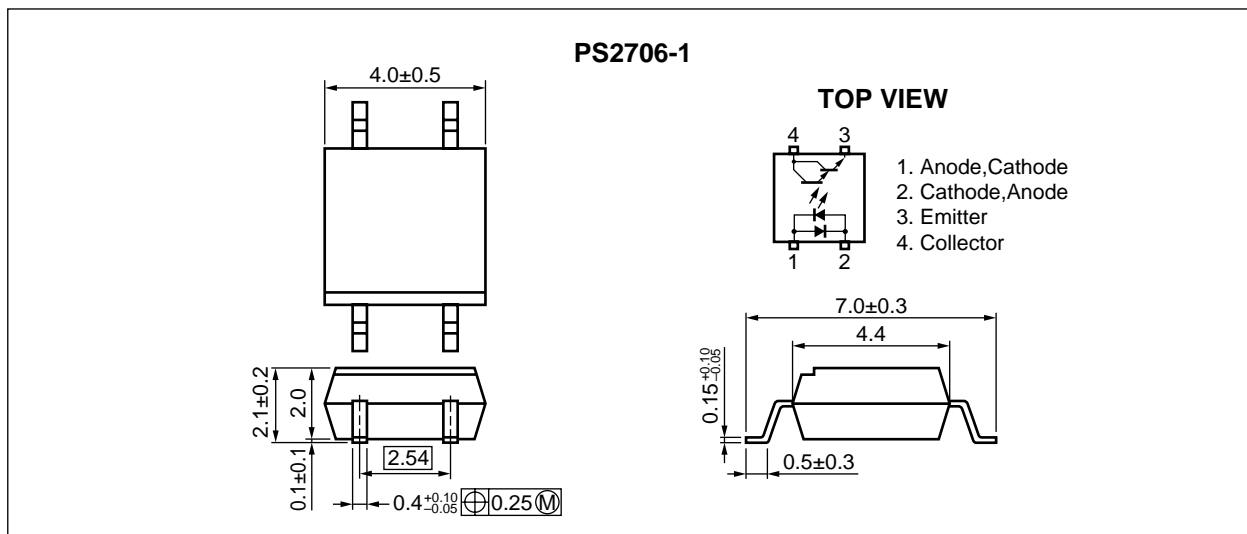
- Hybrid IC
- Telephone, Exchange equipment
- FA/OA equipment
- Programmable logic controllers

ORDERING INFORMATION

Part Number	Package	Safety Standard Approval
PS2706-1	4-pin SOP	Standard specification products • UL approved
PS2706-1-V	4-pin SOP	VDE0884 specification products (Option)

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Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

★ PACKAGE DIMENSIONS (in millimeters)



ABSOLUTE MAXIMUM RATINGS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	I_F	± 50	mA
	Power Dissipation Derating	$\Delta P_D/^{\circ}\text{C}$	0.8	mW/ $^{\circ}\text{C}$
	Power Dissipation	P_D	80	mW
	Peak Forward Current ^{*1}	I_{FP}	± 1	A
Transistor	Collector to Emitter Voltage	V_{CEO}	40	V
	Emitter to Collector Voltage	V_{ECO}	6	V
	Collector Current	I_C	200	mA
	Power Dissipation Derating	$\Delta P_C/^{\circ}\text{C}$	1.5	mW/ $^{\circ}\text{C}$
	Power Dissipation	P_C	150	mW
Isolation Voltage ^{*2}		BV	3 750	Vr.m.s.
Operating Ambient Temperature		T_A	-55 to $+100$	$^{\circ}\text{C}$
Storage Temperature		T_{stg}	-55 to $+150$	$^{\circ}\text{C}$

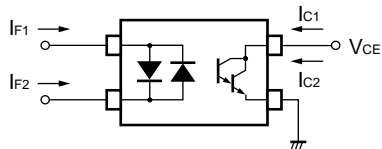
*1 $PW = 100\text{ }\mu\text{s}$, Duty Cycle = 1 %

*2 AC voltage for 1 minute at $T_A = 25\text{ }^{\circ}\text{C}$, RH = 60 % between input and output

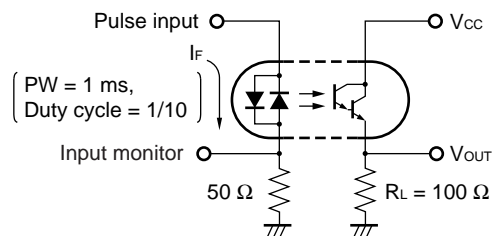
ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V_F	$I_F = \pm 5\text{ mA}$		1.1	1.4	V
	Terminal Capacitance	C_t	$V = 0\text{ V}$, $f = 1\text{ MHz}$		60		pF
Transistor	Collector to Emitter Dark Current	I_{CEO}	$I_F = 0\text{ mA}$, $V_{CE} = 40\text{ V}$			400	nA
Coupled	Current Transfer Ratio (I_C/I_F)	CTR	$I_F = \pm 1\text{ mA}$, $V_{CE} = 2\text{ V}$	200	2 000		%
	CTR Ratio ^{*1}	CTR1/ CTR2	$I_F = \pm 1\text{ mA}$, $V_{CE} = 2\text{ V}$	0.3	1.0	3.0	
	Collector Saturation Voltage	$V_{CE(sat)}$	$I_F = \pm 1\text{ mA}$, $I_C = 2\text{ mA}$			1.0	V
	Isolation Resistance	R_{I-O}	$V_{I-O} = 1\text{ kV}_{DC}$	10^{11}			Ω
	Isolation Capacitance	C_{I-O}	$V = 0\text{ V}$, $f = 1\text{ MHz}$		0.4		pF
	Rise Time ^{*2}	t_r	$V_{CC} = 5\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\text{ }\Omega$		200		μs
	Fall Time ^{*2}	t_f			200		

*1 $CTR1 = I_{C1}/I_{F1}$, $CTR2 = I_{C2}/I_{F2}$

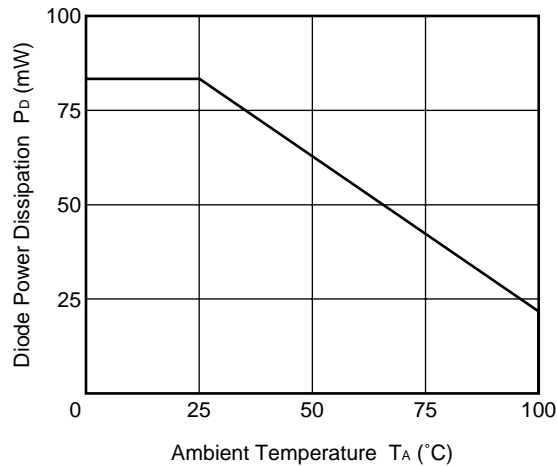


*2 Test circuit for switching time

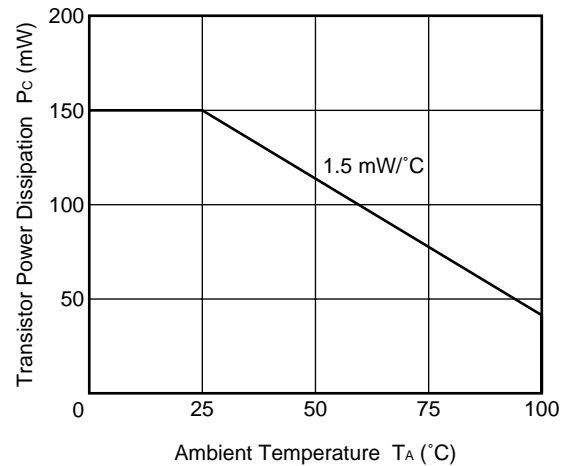


★ TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise specified)

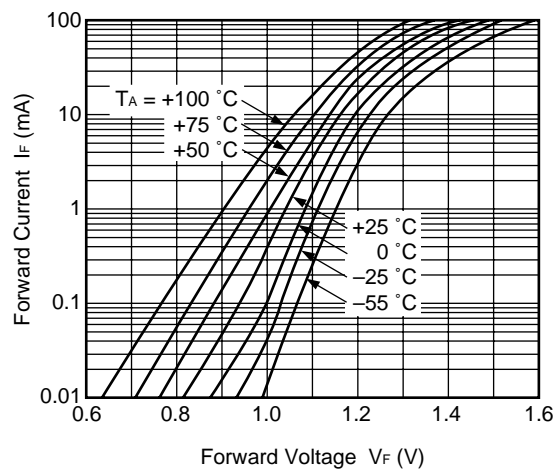
DIODE POWER DISSIPATION vs.
AMBIENT TEMPERATURE



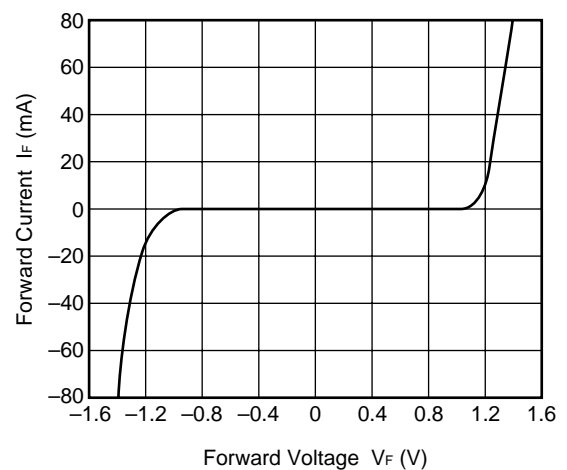
TRANSISTOR POWER DISSIPATION vs.
AMBIENT TEMPERATURE



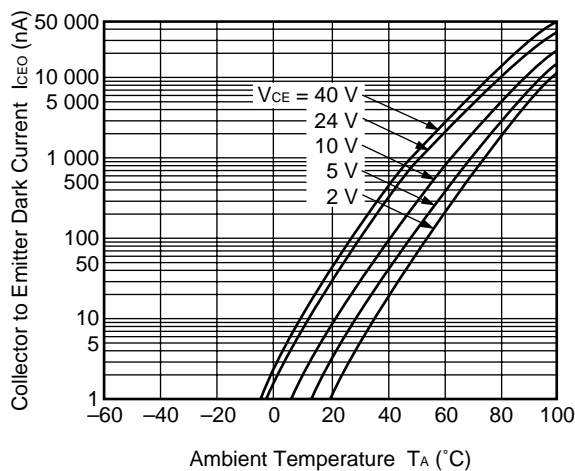
FORWARD CURRENT vs.
FORWARD VOLTAGE



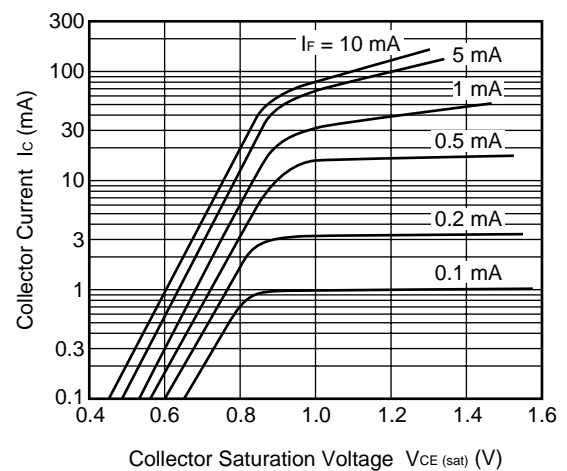
FORWARD CURRENT vs.
FORWARD VOLTAGE



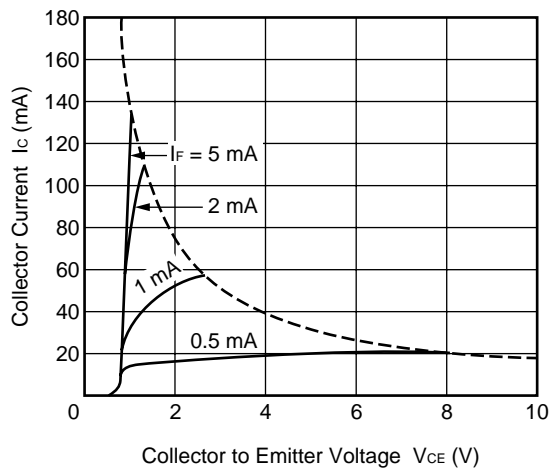
COLLECTOR TO EMITTER DARK
CURRENT vs. AMBIENT TEMPERATURE



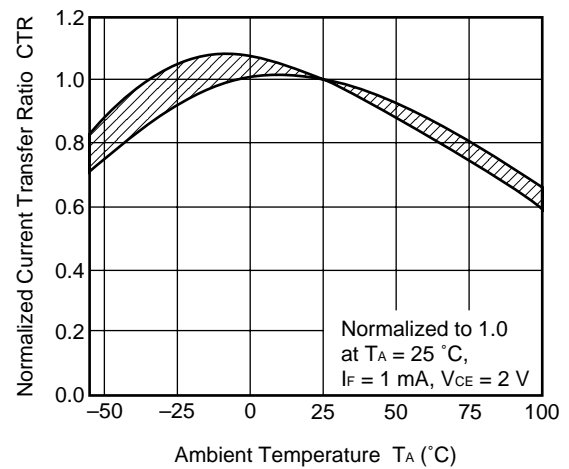
COLLECTOR CURRENT vs.
COLLECTOR SATURATION VOLTAGE



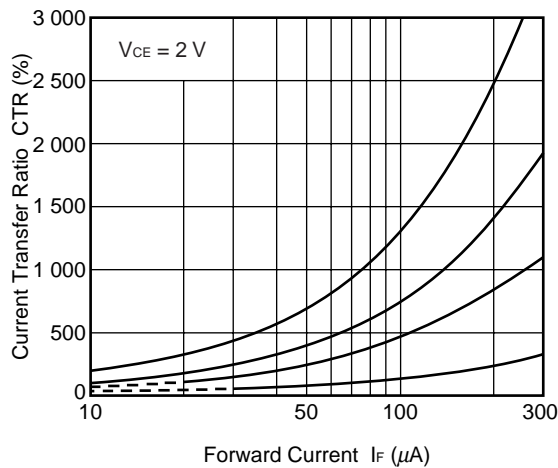
COLLECTOR CURRENT vs.
COLLECTOR TO EMITTER VOLTAGE



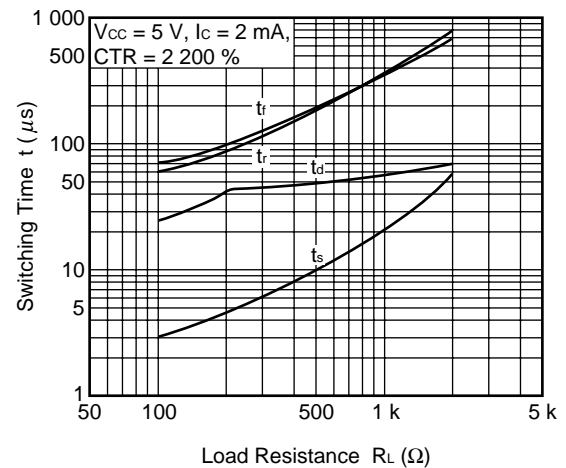
NORMALIZED CURRENT TRANSFER
RATIO vs. AMBIENT TEMPERATURE



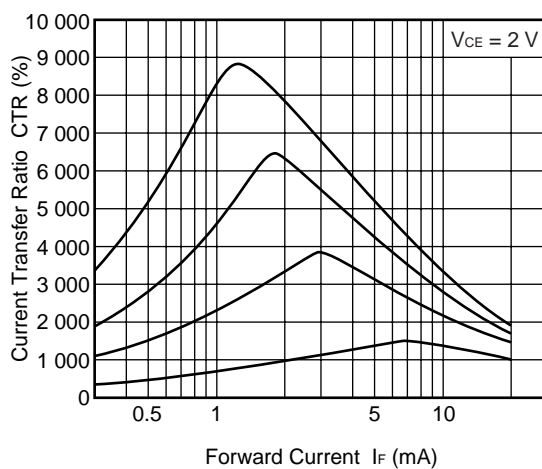
CURRENT TRANSFER RATIO vs.
FORWARD CURRENT



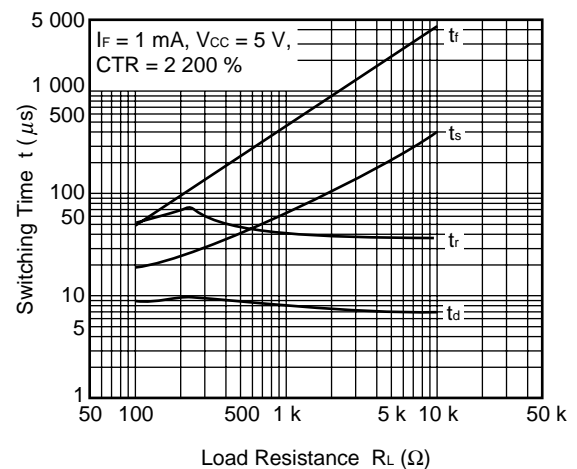
SWITCHING TIME vs.
LOAD RESISTANCE

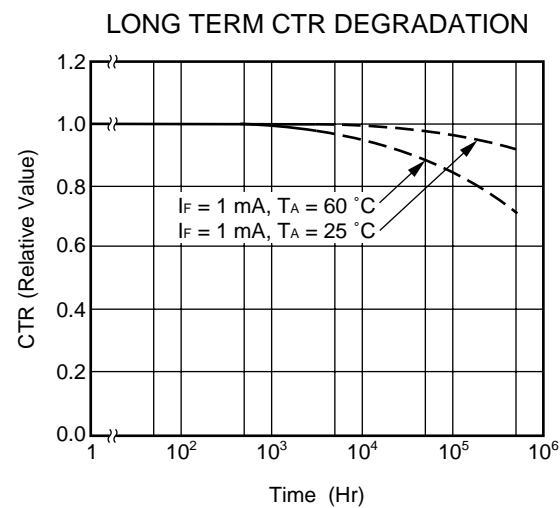
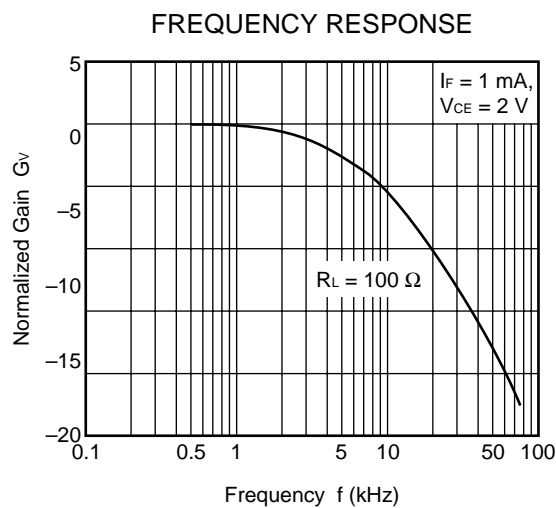


CURRENT TRANSFER RATIO vs.
FORWARD CURRENT



SWITCHING TIME vs.
LOAD RESISTANCE

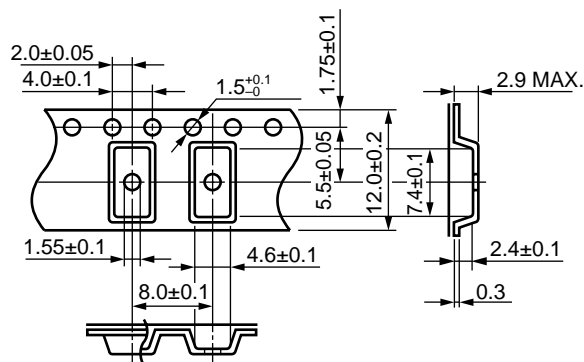




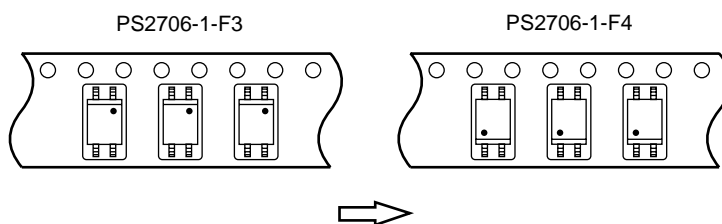
Remark The graphs indicate nominal characteristics.

★ TAPING SPECIFICATIONS (in millimeters)

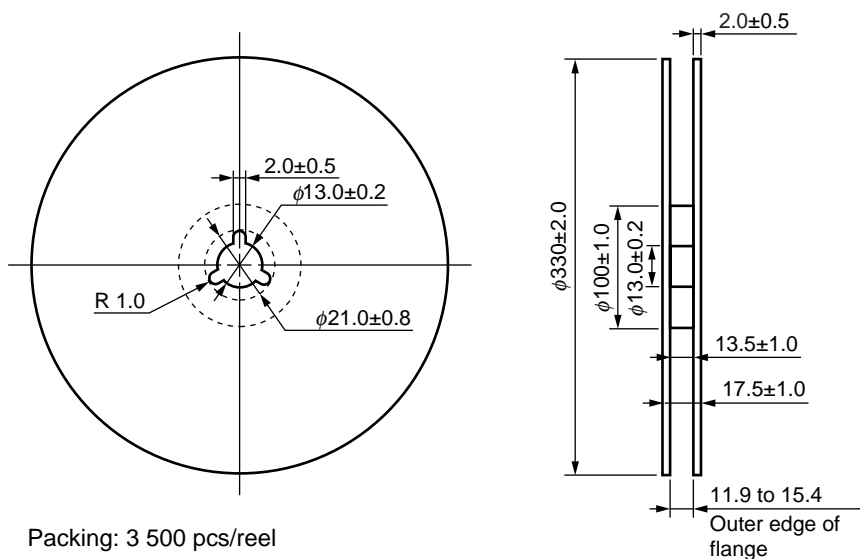
Outline and Dimensions (Tape)



Tape Direction



Outline and Dimensions (Reel)



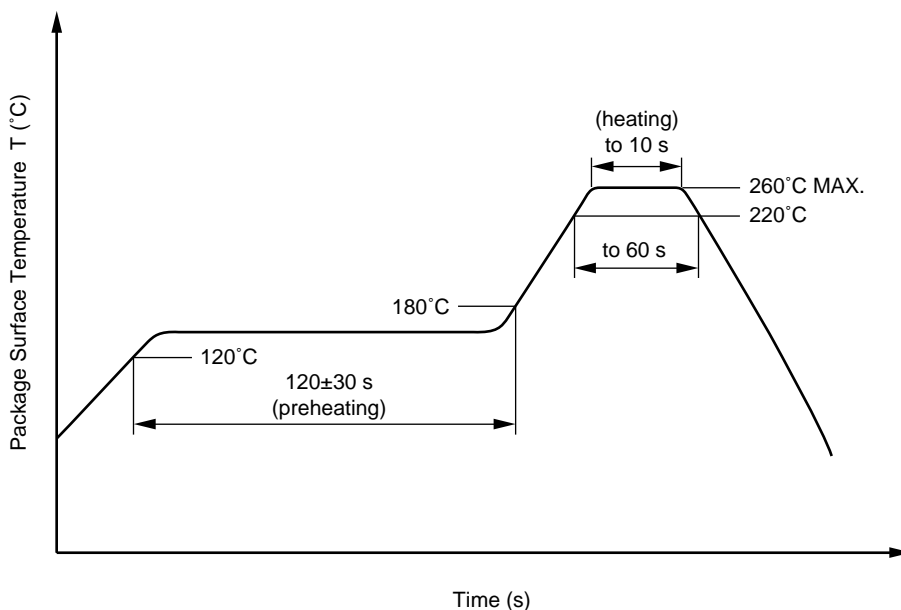
★ NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

- Peak reflow temperature 260°C or below (package surface temperature)
- Time of peak reflow temperature 10 seconds or less
- Time of temperature higher than 220°C 60 seconds or less
- Time to preheat temperature from 120 to 180°C 120±30 s
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Cautions

- Fluxes
Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

★ USAGE CAUTIONS

1. Protect against static electricity when handling.
2. Avoid storage at a high temperature and high humidity.

SPECIFICATION OF VDE MARKS LICENSE DOCUMENT (VDE0884)

Parameter	Symbol	Speck	Unit
Application classification (DIN VDE 0109) for rated line voltages ≤ 300 Vr.m.s. for rated line voltages ≤ 600 Vr.m.s.		IV III	
Climatic test class (DIN IEC 68 Teil 1/09.80)		55/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.2 \times U_{IORM}$, $P_d < 5$ pC	U_{IORM} U_{pr}	710 850	V_{peak} V_{peak}
★ Test voltage (partial discharge test, procedure b for all devices test) $U_{pr} = 1.6 \times U_{IORM}$, $P_d < 5$ pC	U_{pr}	1 140	V_{peak}
Highest permissible overvoltage	U_{TR}	6 000	V_{peak}
Degree of pollution (DIN VDE 0109)		2	
Clearance distance		> 5	mm
Creepage distance		> 5	mm
Comparative tracking index (DIN IEC 112/VDE 0303 part 1)	CTI	175	
Material group (DIN VDE 0109)		III a	
Storage temperature range	T_{stg}	-55 to +150	°C
Operating temperature range	T_A	-55 to +100	°C
Isolation resistance, minimum value $V_{IO} = 500$ V dc at $T_A = 25$ °C $V_{IO} = 500$ V dc at T_A MAX. at least 100 °C	Ris MIN. Ris MIN.	10^{12} 10^{11}	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I_F , $P_{si} = 0$) Power (output or total power dissipation) Isolation resistance $V_{IO} = 500$ V dc at $T_A = 175$ °C (T_{si})	T_{si} I_{si} P_{si} Ris MIN.	150 200 300 10^9	°C mA mW Ω

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M8E 00.4-0110

SAFETY INFORMATION ON THIS PRODUCT

Caution	GaAs Products	<p>The product contains gallium arsenide, GaAs. GaAs vapor and powder are hazardous to human health if inhaled or ingested.</p> <ul style="list-style-type: none"> • Do not destroy or burn the product. • Do not cut or cleave off any part of the product. • Do not crush or chemically dissolve the product. • Do not put the product in the mouth. <p>Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.</p>
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